

6MBI180VB-120-50

IGBT Modules

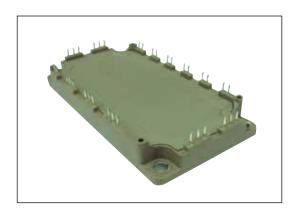
IGBT MODULE (V series) 1200V / 180A / 6 in one package

■ Features

Compact Package P.C.Board Mount Low Vce (sat)

■ Applications

Inverter for Motor Drive
AC and DC Servo Drive Amplifier
Uninterruptible Power Supply
Industrial machines, such as welding machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units		
	Collector-Emitter voltage		Vces			1200	V	
	Gate-Emitter voltage		V _{GES}			±20	V	
rter	Collector current		Ic	Continuous	Tc=80°C	150		
er			Ic pulse	1ms	Tc=80°C	400	٨	
Inve			-lc			150	Α	
			-lc pulse	1ms		400		
	Collector power dissipation		Pc	1 device		835	W	
Junction temperature		Tj			175			
Operating junciton temperature (under switching conditions)			Tjop			150	°C	
Case temperature		Тс	125					
Storage temperature		Tstg	-40 ~ +125					
Iso	lation voltage	Between terminal and copper base (*1) Between thermistor and others (*2)	Viso	AC : 1min.		2500	VAC	
Sci	rew torque	Mounting (*3)	-	M5		3.5	N m	

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable value: 2.5-3.5 Nm (M5)

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● Electrical characteristics (at Tj= 25°C unless otherwise specified)

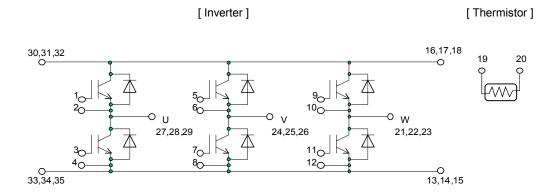
14.	ms	Cumbala	Conditions		Characteristics			Units
πe	ills	Symbols			min.	typ.	max.	Units
	Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	1.0	mA
Inverter	Gate-Emitter leakage current	Iges	$V_{CE} = 0V$, $V_{GE} = \pm 20V$		-	-	200	nA
	Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 200mA		6.0	6.5	7.0	V
	Collector-Emitter saturation voltage	.,	V _{GE} = 15V I _C = 200A	Tj=25°C	-	2.85	3.30	V
		V _{CE (sat)} (terminal)		Tj=125°C	-	3.20	-	
		(terriniar)		Tj=150°C	-	3.25	-	
		.,	V _{GE} = 15V I _C = 200A	Tj=25°C	-	1.85	2.30	
		V _{CE (sat)} (chip)		Tj=125°C	-	2.20	-	
		(GIIIP)		Tj=150°C	-	2.25	-	
	Input capacitance	Cies	V _{CE} = 10V, V _{GE} = 0V, f = 1MHz		-	16.5	-	nF
	Turn-on time	ton	V _{cc} = 600V I _c = 200A V _{GE} = +15 / -15V R _G = 1.2Ω		-	0.39	1.20	µs
Ne		tr			-	0.09	0.60	
=		tr (i)			-	0.03	-	
	Turn-off time	toff			-	0.53	1.00	
	Turn-off time	tf			-	0.06	0.30	
	Forward on voltage		Tj=25°C Tj=125°C Tj=125°C Tj=150°C Tj=150°C	Tj=25°C	-	2.70	3.15	V
		V _F (terminal)		Tj=125°C	-	2.85	-	
		(terrillial)		Tj=150°C	-	2.80	-	
		.,	I _F = 200A	Tj=25°C	-	1.70	2.15	
		V _F (chip)		Tj=125°C	-	1.85	-	
		(GIIIP)		Tj=150°C	-	1.80	-	
	Reverse recovery time	trr	I _F = 200A		-	-	0.35	μs
ţ	Pasiatanas	Б	T = 25°C		-	5000	-	Ω
Thermistor	Resistance	R	T = 100°C		465	495	520	
를	B value	В	T = 25 / 50°C		3305	3375	3450	K

● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units	
items		Conditions	min.	typ.	max.	Units	
Thermal registeres (4 device)	Rth(j-c)	Inverter IGBT	-	-	0.18		
Thermal resistance (1device)		Inverter FWD	-	-	0.29	°C/W	
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	-	0.05	-		

Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Equivalent Circuit Schematic

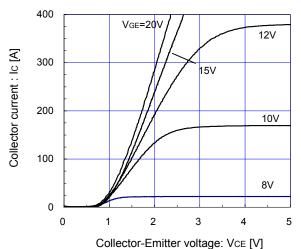


■ Characteristics (Representative)

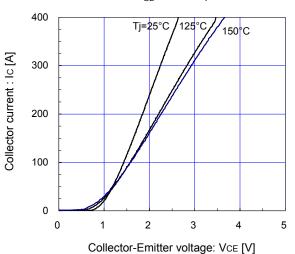
[Inverter]

Collector current vs. Collector-Emitter voltage (typ.)

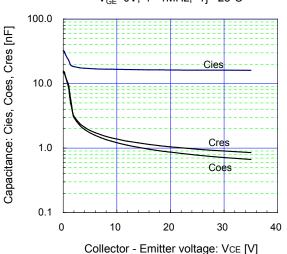
Tj= 25°C / chip

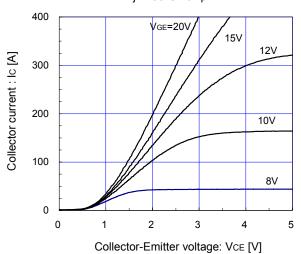


 $[Inverter\] \\ Collector\ current\ vs.\ Collector-Emitter\ voltage\ (typ.) \\ V_{GE} = 15V\ /\ chip$

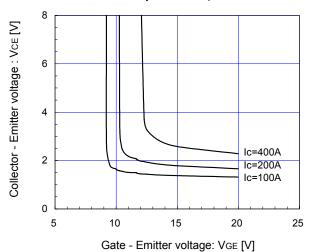


 $[Inverter] \\ Capacitance vs. Collector-Emitter voltage (typ.) \\ V_{GF}=0V, \ f=1MHz, \ Tj=25^{\circ}C$





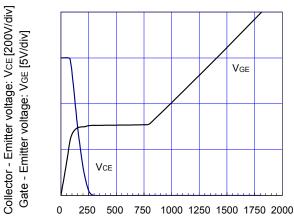
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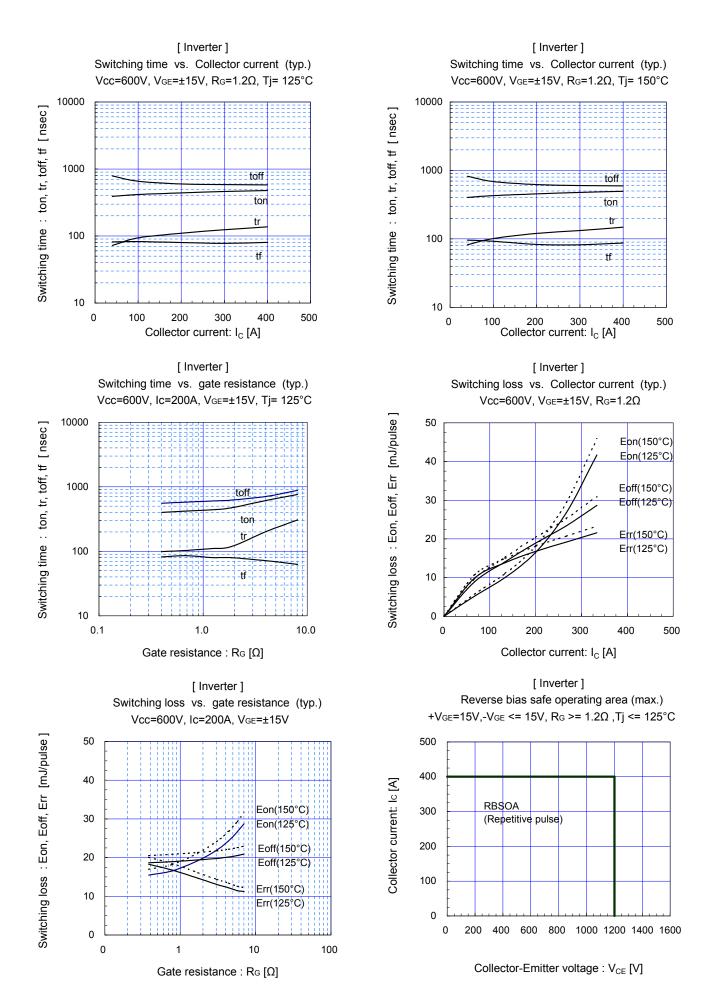
[Inverter]

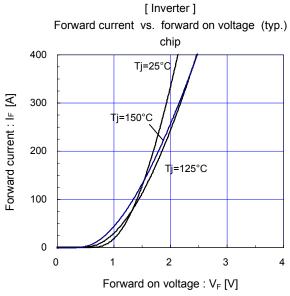
Dynamic gate charge (typ.)

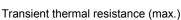
Vcc=600V, Ic=200A, Tj= 25°C

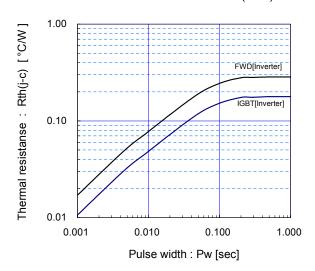


Gate charge: Qg [nC]

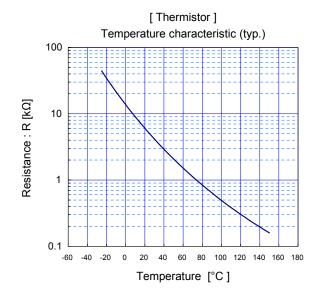




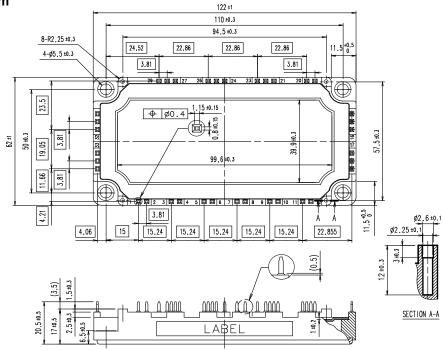




[Inverter] Reverse recovery characteristics (typ.) Vcc=600V, VgE=±15V, Rg=1.2Ω 1000 Reverse recovery current : Irr [A] Reverse recovery time : trr [nsec] Irr(150°C) Irr(125°C) trr(150°C) trr(125°C) 100 10 100 400 500 600 0 200 300 Forward current : I_F [A]



■ Outline Drawings, mm



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